

# **SWITCHMODE**<sup>™</sup> **Power Rectifiers**

### **BYW80-200**

This state-of-the-art device is designed for use in switching power supplies, inverters and as free wheeling diodes.

#### **Features**

- Ultrafast 35 Nanosecond Recovery Time
- 175°C Operating Junction Temperature
- Popular TO-220 Package
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Low Forward Voltage
- Low Leakage Current
- High Temperature Glass Passivated Junction
- Pb-Free Package is Available\*

#### **Mechanical Characteristics**

- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260 °C Max. for 10 Seconds

#### **MAXIMUM RATINGS**

Rating	Symbol	Values	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	200	V
Average Rectified Forward Current Total Device, (Rated $V_R$ ), $T_C = 150  ^{\circ}C$	I <sub>F(AV)</sub>	8.0	Α
Peak Repetitive Forward Current (Rated $V_R$ , Square Wave, 20 kHz), $T_C$ = 150 °C	I <sub>FM</sub>	16	Α
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I <sub>FSM</sub>	100	Α
Operating Junction Temperature and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +175	°C

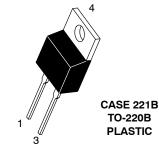
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, <u>SOLDERRM/D</u>.

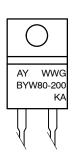
1

## **ULTRAFAST RECTIFIERS 8.0 AMPERES**, 200 VOLTS





#### MARKING DIAGRAM



A = Assembly Location

Y = Year
WW = Work Week
BYW80-200 = Device Code
G = Pb-Free Package
KA = Diode Polarity

#### **ORDERING INFORMATION**

Device	Package	Shipping
BYW80-200G	TO-220 (Pb-Free)	50 Units/Rail

#### **DISCONTINUED** (Note 1)

BYW80-200	TO-220	50 Units/Rail
	l .	I

DISCONTINUED: This device is not available. Please contact your onsemi representative for information. The most current information on this device may be available on <a href="https://www.onsemi.com">www.onsemi.com</a>.

#### THERMAL CHARACTERISTICS

Rating	Symbol	Values	Unit		
Maximum Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	3.0	°C/W		
ELECTRICAL CHARACTERISTICS					

Maximum Instantaneous Forward Voltage (Note 2) (i <sub>F</sub> = 7.0 A, $T_C$ = 100 °C) (i <sub>F</sub> = 22 A, $T_C$ = 25 °C)	VF	0.85 1.25	V
Maximum Instantaneous Reverse Current (Note 2) (Rated dc Voltage, $T_J$ = 100 °C) (Rated dc Voltage, $T_J$ = 25 °C)	i <sub>R</sub>	1 0.01	mA
Maximum Reverse Recovery Time ( $I_F = 1.0 \text{ A}$ , $di/dt = 50 \text{ A}/\mu\text{s}$ ) ( $I_F = 0.5 \text{ A}$ , $I_R = 1.0 \text{ A}$ , $I_{REC} = 0.25 \text{ A}$ )	t <sub>rr</sub>	35 25	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

<sup>2.</sup> Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

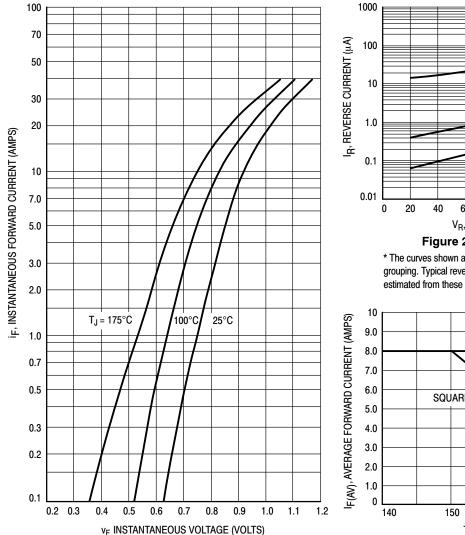


Figure 1. Typical Forward Voltage

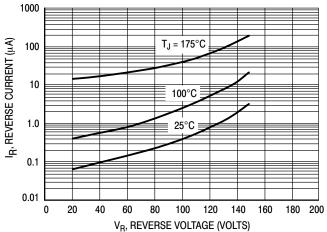


Figure 2. Typical Reverse Current\*

<sup>\*</sup> The curves shown are typical for the highest voltage device in the grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if V<sub>R</sub> is sufficiently below rated V<sub>R</sub>.

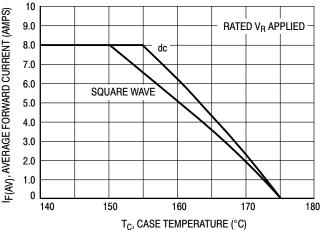
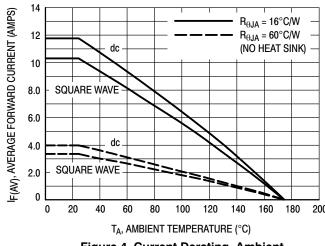


Figure 3. Current Derating, Case



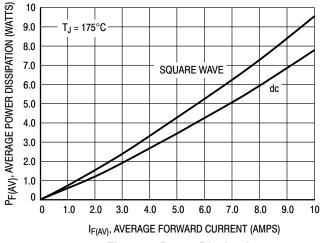


Figure 4. Current Derating, Ambient

Figure 5. Power Dissipation

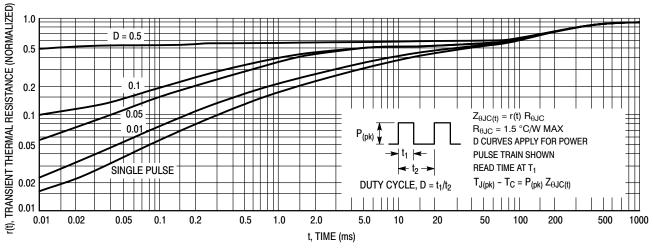


Figure 6. Thermal Response

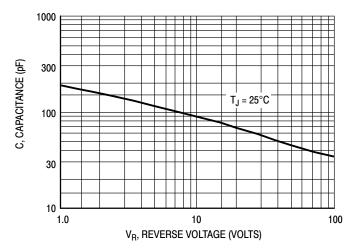


Figure 7. Typical Capacitance

#### BYW80-200

#### **REVISION HISTORY**

Ī	Revision	Description of Changes	Date
	4	Rebranded the Data Sheet to onsemi format. BYW80-200 OPN Marked as Discontinued.	05/23/2025





TO-220, 2-LEAD CASE 221B-04 **ISSUE F** 

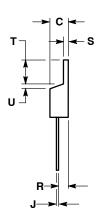
**DATE 12 APR 2013** 

#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.

	INCHES MILLIN		IETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.595	0.620	15.11	15.75
В	0.380	0.405	9.65	10.29
С	0.160	0.190	4.06	4.82
D	0.025	0.039	0.64	1.00
F	0.142	0.161	3.61	4.09
G	0.190	0.210	4.83	5.33
Н	0.110	0.130	2.79	3.30
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.14	1.52
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.14	1.39
T	0.235	0.255	5.97	6.48
U	0.000	0.050	0.000	1.27

Q Н



STYLE 1: PIN 1. CATHODE 2. N/A 3. ANODE

PIN 1. ANODE 2. N/A 3. CATHODE 4. ANODE

Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. **DOCUMENT NUMBER:** 98ASB42149B **DESCRIPTION:** TO-220, 2-LEAD PAGE 1 OF 1

onsemi and ONSEMi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, Onsemi, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <a href="www.onsemi.com/site/pdf/Patent-Marking.pdf">www.onsemi.com/site/pdf/Patent-Marking.pdf</a>. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA class 3 medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase

#### ADDITIONAL INFORMATION

**TECHNICAL PUBLICATIONS:** 

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$ 

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales